

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	165	(hbt (heterojunction adj bipolar adj transistor)) and sige	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 13:57
2	BRS	L2	152	1 and base	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 13:57
3	BRS	L3	114	2 and (thick\$4 width)	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 13:58
4	BRS	L4	92	3 and (graded concentration)	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 13:58
5	BRS	L5	60	4 and @ay<1996	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 14:00
6	BRS	L6	71	4 and @ay<1997	USPAT; EPO; JPO; Derwent; IBM TDB	2001/03/19 14:01

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
3	BRS	L3	20	(hbt (heterojunction adj bipolar adj transistor)) and sigc and carbon	USPAT; EPO; JPO	2000/06/13 08:56		
4	IS&R	L4	52	("257/19").CCLS.	USPAT	2000/06/13 09:10		
5	BRS	L5	169	sigc and carbon and si and boron	USPAT	2000/06/13 09:21		
6	BRS	L6	3	5 and ((boron b) adj diffusion)	USPAT	2000/06/13 09:27		
7	IS&R	L7	266	("257/200").CCLS.	USPAT	2000/06/13 09:41		
8	BRS	L8	10	257/200.ccls. and sigc	USPAT	2000/06/13 09:42		